

Supplementary Information

Galvanic Displaced Ultra-long $\text{Pb}_x\text{Se}_y\text{Ni}_z$ Hollow Nanofibers with High Thermopower

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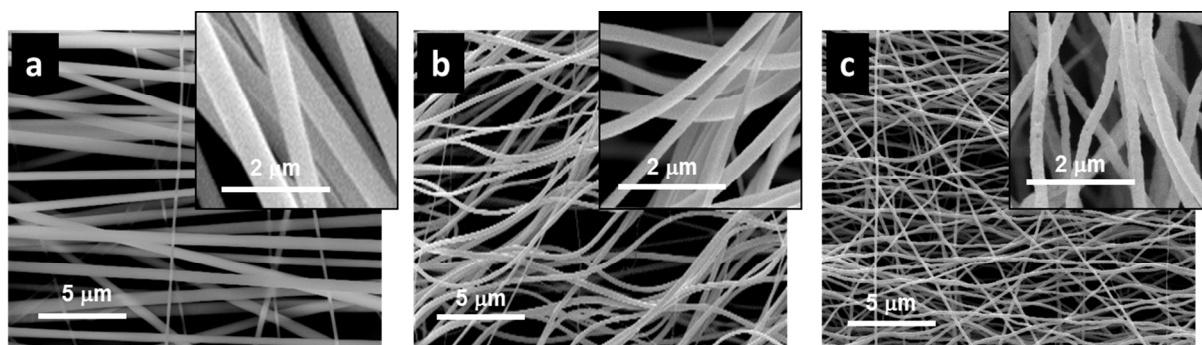


Figure S1. SEM images of (a) electrospun PVP/Ni acetate nanofibers, (b) NiO nanofibers, (c) Ni nanofibers.

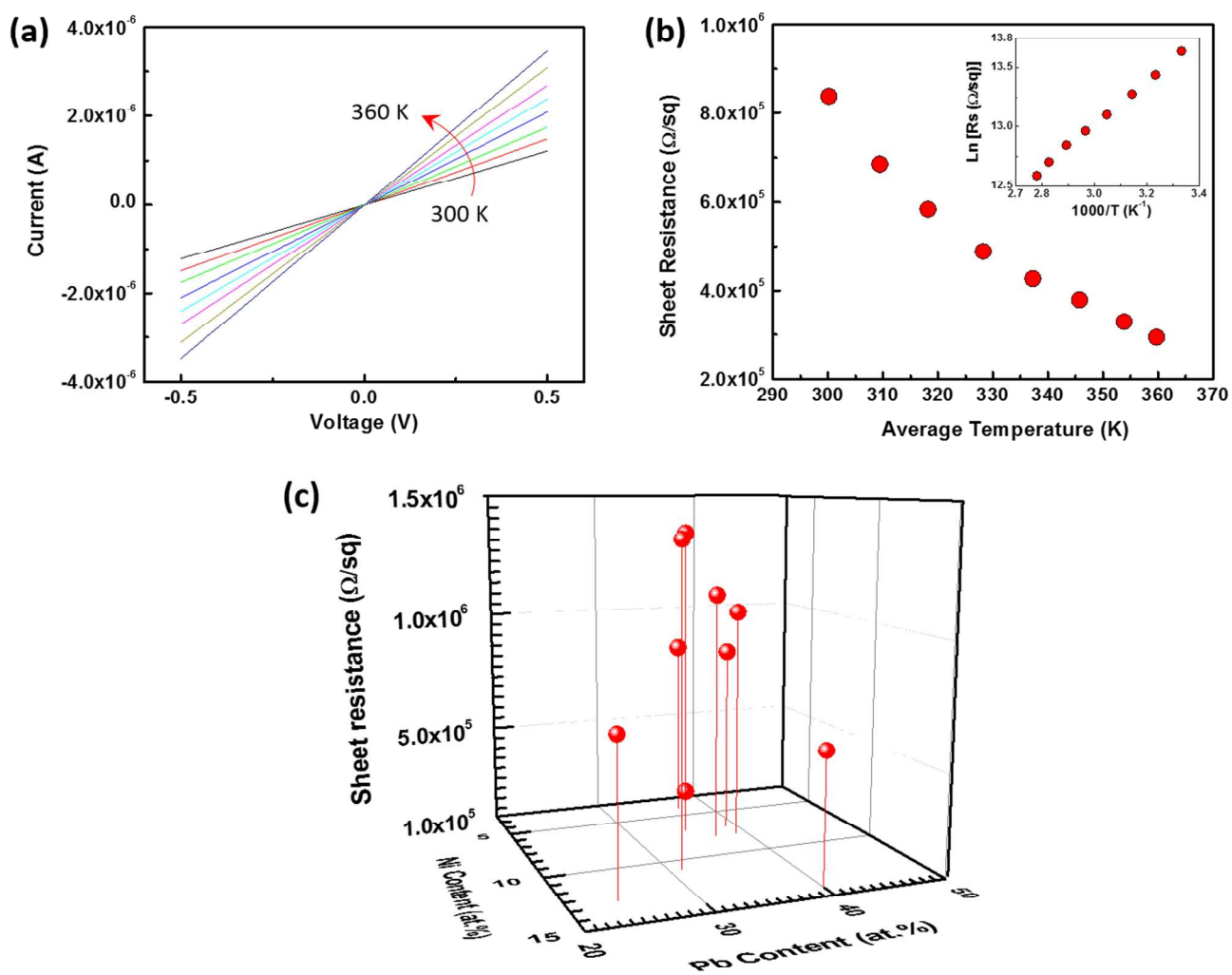


Figure S2. Temperature dependent (a) I-V characterization and (b) sheet resistance of $\text{Pb}_{37}\text{Se}_{59}\text{Ni}_4$ NF mat. (c) 3D plot of Seebeck coefficient of $\text{Pb}_x\text{Se}_y\text{Ni}_z$ nanofiber mat at 300 K as a function of Ni and Pb content.

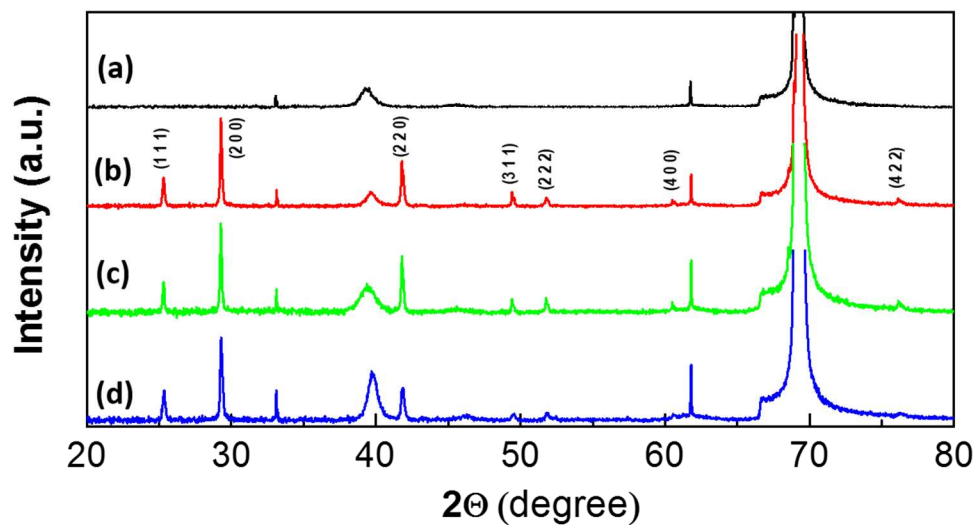


Figure S3. XRD pattern of (a) substrate, (b) $\text{Pb}_{31}\text{Se}_{62}\text{Ni}_7$, (c) $\text{Pb}_{35}\text{Se}_{58}\text{Ni}_7$, (d) $\text{Pb}_{37}\text{Se}_{59}\text{Ni}_4$ hollow nanofiber mats. Substrate peaks are contributed from Si, Pt electrode and sample holder.

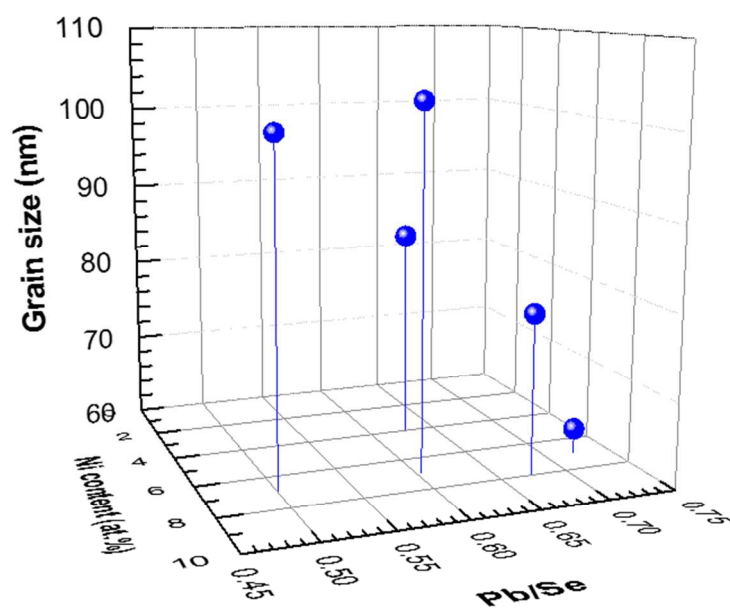


Figure S4. 3D plot of $\text{Pb}_x\text{Se}_y\text{Ni}_z$ nanofiber mats' grain size as a function of Ni content and the ratio of Pb to Se content.

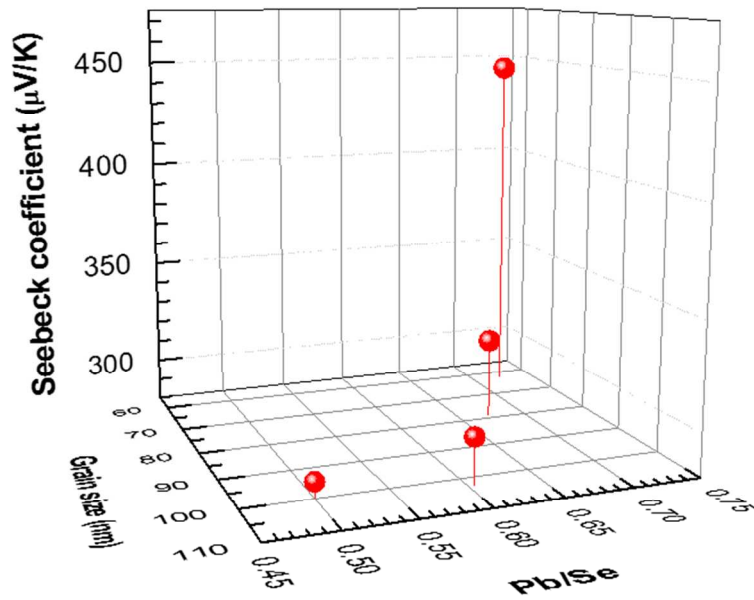


Figure S5. 3D plot of $\text{Pb}_x\text{Se}_y\text{Ni}_z$ nanofiber mats' Seebeck coefficient at 300 K as a function of Ni content and the ratio of Pb to Se content.

Reference:

1. Jung, H.; Park, D. Y.; Xiao, F.; Lee, K. H.; Choa, Y. H.; Yoo, B.; Myung, N. V., Electrodeposited Single Crystalline PbTe Nanowires and Their Transport Properties. *J Phys Chem C* **2011**, *115* (7), 2993-2998.
2. Wang, H.; Pei, Y. Z.; LaLonde, A. D.; Snyder, G. J., Heavily Doped p-Type PbSe with High Thermoelectric Performance: An Alternative for PbTe. *Advanced Materials* **2011**, *23* (11), 1366-1370.
3. Kishimoto, K.; Koyanagi, T., Preparation of sintered degenerate n-type PbTe with a small grain size and its thermoelectric properties. *J Appl Phys* **2002**, *92* (5), 2544-2549.